



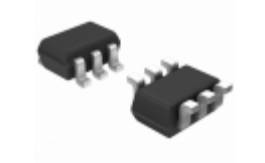
	<p>SI1403BDL-T1-E3</p>
	<p>Hersteller-Teilenummer: SI1403BDL-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 1.4A SC70-6</p> <p>Datenblätter:  SI1403BDL-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 19904 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1403BDL-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 1.4A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	19904 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Verlustleistung (max)	568mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.4A (Ta)
Rds On (Max) @ Id, Vgs	150 mOhm @ 1.5A, 4.5V
VGS (th) (Max) @ Id	1.3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	4.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)








SI1403BDL-T1-E3 ist neu im Original, Suche SI1403BDL-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1403BDL-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1403BDL-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1403CDL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 2.1A SC-70-6</p>	 <p>SI1403BDL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 1.5A SC70-6</p>	 <p>SI1402DH-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 2.7A SOT363</p>	 <p>SI1403BDL-T1-GE3 Vishay Vishay SMD</p>
 <p>SI1402DH-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 2.7A SOT363</p>	 <p>SI1402DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.7A SOT363</p>	 <p>SI1403CDL-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 2.1A SC-70-6</p>	 <p>SI1402DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.7A SOT363</p>

heiße Teile

Mehr

 SI1307EDL-T1-E3	 SI1307EDL-T1-GE3	 SI1307EDL-T1-GE3	 SI1308EDL	 SI1308EDL-T1-GE3
 SI1308EDL-T1-GE3	 SI13132CNU	 SI1315DL-T1-GE3	 SI1315DL-T1-GE3	 SI1317DL-T1-GE3
 SI1317DL-T1-GE3	 SI1330EDL-T1-E3	 SI1330EDL-T1-E3	 SI1330EDL-T1-GE3	 SI1330EDL-T1-GE3
 SI1400DL-T1	 SI1400DL-T1-E3	 SI1400DL-T1-E3	 SI1400DL-T1-GE3	 SI1400DL-T1-GE3
 SI1401EDH-T1-GE3	 SI1401EDH-T1-GE3	 SI1402DH-T1-GE3	 SI1402DH-T1-GE3	 SI1403BDL-T1-E3
 SI1403BDL-T1-GE3	 SI1403BDL-T1-GE3	 SI1403CDL-T1-GE3	 SI1403CDL-T1-GE3	 SI1403DL
 SI1403DL-T1	 SI1403DL-T1-E3	 SI1403DL-T1-GE3	 SI1404BDH-T1-E3	 SI1404BDH-T1-E3
 SI1404DH-T1	 SI1404DH-T1-E3	 SI1404DH-T1-GE3	 SI1404DL-T1-GE3	 SI1405BDH-T1-E3
 SI1405BDH-T1-E3	 SI1405BDH-T1-GE3	 SI1405BDH-T1-GE3	 SI1405DL-T1	 SI1405DL-T1-E3
 SI1405DL-T1-E3	 SI1406DH	 SI1406DH-T1	 SI1406DH-T1-E3	 SI1406DH-T1-E3

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